

# ADJUSTABLE PRECISION ZENER SHUNT REGULATOR

## ZHT431

ISSUE 2 – FEBRUARY 1997

### DEVICE DESCRIPTION

The ZHT431 is a three terminal adjustable shunt regulator offering excellent temperature stability and output current handling capability up to 100mA. The device offers extended operating temperature range working from -55 to +125°C. The output voltage may be set to any chosen voltage between 2.5 and 20 volts by selection of two external divider resistors.

The devices can be used as a replacement for zener diodes in many applications requiring an improvement in zener performance.

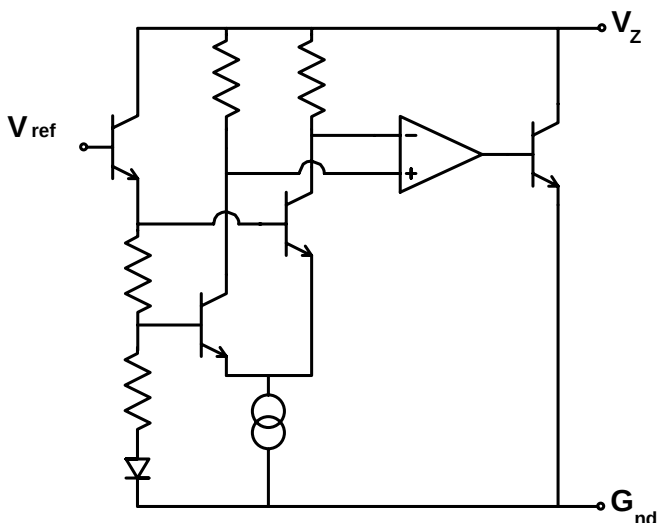
### FEATURES

- Surface mount SO8, SOT89, SOT223 and SOT23 packages
- TO92 package
- 2% and 1% tolerance
- Maximum temperature coefficient 67 ppm/°C
- Temperature compensated for operation over the full temperature range
- Programmable output voltage
- 50μA to 100mA current sink capability
- Low output noise
- Wide temperature range -55 to +125°C

### APPLICATIONS

- Series and Shunt regulator
- Voltage monitor
- Over voltage/ under voltage protection
- Switch mode power supplies

### SCHEMATIC DIAGRAM



## ABSOLUTE MAXIMUM RATING

|                                   |              |
|-----------------------------------|--------------|
| Cathode Voltage (V <sub>Z</sub> ) | 20V          |
| Cathode Current                   | 150mA        |
| Operating Temperature             | -55 to 125°C |
| Storage Temperature               | -55 to 150°C |

## Recommended Operating Conditions

|                 |                  |       |
|-----------------|------------------|-------|
|                 | Min              | Max   |
| Cathode Voltage | V <sub>ref</sub> | 20V   |
| Cathode Current | 50μA             | 100mA |

## Power Dissipation (T<sub>amb</sub>=25°C)

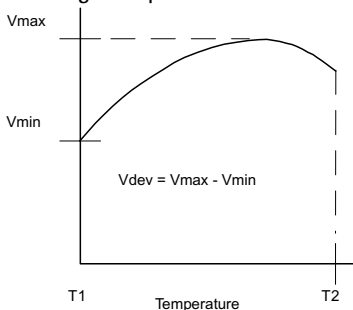
|                             |       |
|-----------------------------|-------|
| (T <sub>jmax</sub> = 150°C) |       |
| SOT23                       | 330mW |
| TO92                        | 780mW |
| SOT223                      | 2W    |
| SO8                         | 780mW |
| SOT89                       | 1.5W  |

## ELECTRICAL CHARACTERISTICS TEST CONDITIONS (Unless otherwise stated):T<sub>amb</sub>=25°C

| PARAMETER                                                                 | SYMBOL                              | VALUE |       |       | UNITS | CONDITIONS                                                                                  |
|---------------------------------------------------------------------------|-------------------------------------|-------|-------|-------|-------|---------------------------------------------------------------------------------------------|
|                                                                           |                                     | MIN   | TYP   | MAX   |       |                                                                                             |
| Reference Voltage                                                         | V <sub>ref</sub>                    | 2.45  | 2.50  | 2.55  | V     | I <sub>L</sub> =10mA (Fig1), V <sub>Z</sub> =V <sub>ref</sub>                               |
|                                                                           |                                     | 2.475 | 2.50  | 2.525 |       |                                                                                             |
| Deviation of Reference Input Voltage over Temperature                     | V <sub>dev</sub>                    |       | 10    | 30    | mV    | I <sub>L</sub> =10mA, V <sub>Z</sub> =V <sub>ref</sub><br>T <sub>a</sub> =full range (Fig1) |
| Ratio of the change in Reference Voltage to the Change in Cathode Voltage | $\frac{\Delta V_{ref}}{\Delta V_Z}$ |       | -1.85 | -2.7  | mV/V  | V <sub>Z</sub> from V <sub>ref</sub> to 10V<br>I <sub>Z</sub> =10mA (Fig2)                  |
|                                                                           |                                     |       | -1.0  | -2.0  | mV/V  | V <sub>Z</sub> from 10V to 20V<br>I <sub>Z</sub> =10mA (Fig2)                               |
| Reference Input Current                                                   | I <sub>ref</sub>                    |       | 0.12  | 1.0   | μA    | R1=10k, R2=O/C, I <sub>L</sub> =10mA (Fig2)                                                 |
| Deviation of Reference Input Current over Temperature                     | ΔI <sub>ref</sub>                   |       | 0.04  | 0.2   | μA    | R1=10k, R2=O/C, I <sub>L</sub> =10mA<br>T <sub>a</sub> =full range (Fig2)                   |
| Minimum Cathode Current for Regulation                                    | I <sub>Zmin</sub>                   |       | 35    | 50    | μA    | V <sub>Z</sub> =V <sub>ref</sub> (Fig1)                                                     |
| Off-state Current                                                         | I <sub>Zoff</sub>                   |       |       | 0.1   | μA    | V <sub>Z</sub> =20V, V <sub>ref</sub> =0V(Fig3) †                                           |
| Dynamic Output Impedance                                                  | R <sub>Z</sub>                      |       |       | 0.75  | Ω     | V <sub>Z</sub> =V <sub>ref</sub> (Fig1), f=0Hz,<br>I <sub>C</sub> =1mA to 100mA             |

Deviation of reference input voltage, V<sub>dev</sub>, is defined as the maximum variation of the reference input voltage over the full temperature range.

The average temperature coefficient of the reference input voltage, V<sub>ref</sub> is defined as:



$$V_{ref} (ppm/^{\circ}C) = \frac{V_{dev} \times 1000000}{V_{ref} (T1 - T2)}$$

The dynamic output impedance, R<sub>Z</sub>, is defined as:

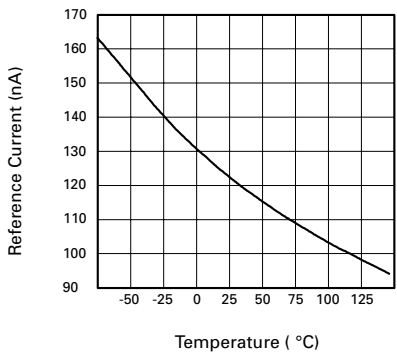
$$R_Z = \frac{\Delta V_Z}{\Delta I_Z}$$

When the device is programmed with two external resistors, R1 and R2, (fig 2), the dynamic output impedance of the overall circuit, R', is defined as:

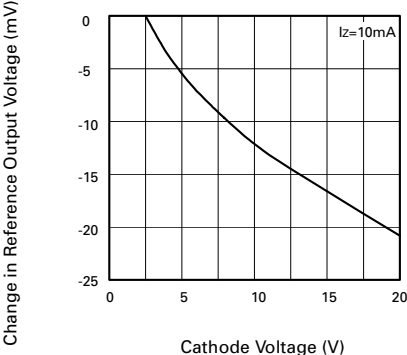
$$R' = R_Z \left(1 + \frac{R1}{R2}\right)$$

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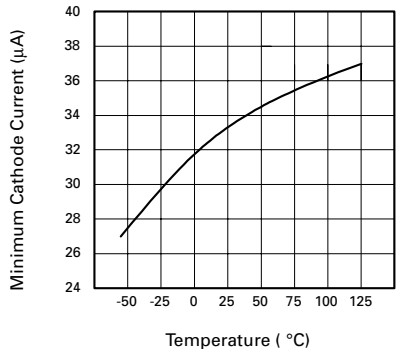
## TYPICAL CHARACTERISTICS



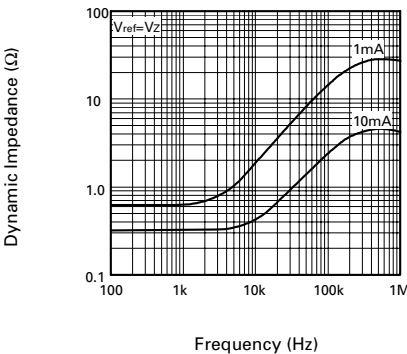
**I<sub>ref</sub> vs. Temperature**



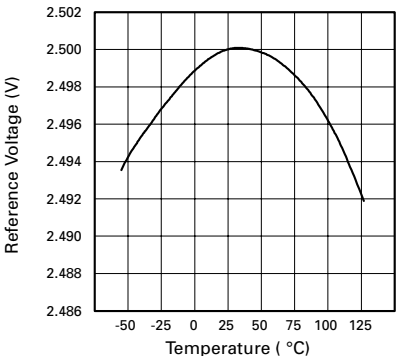
**Change in V<sub>ref</sub> v Cathode Voltage**



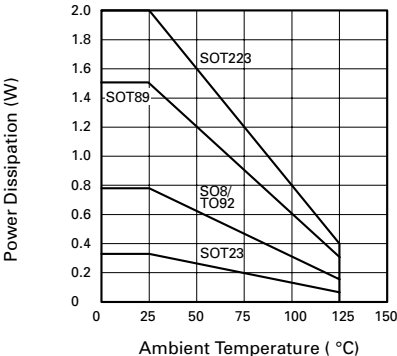
**I<sub>zmin</sub> vs. Temperature**



**Dynamic Impedance v Frequency**

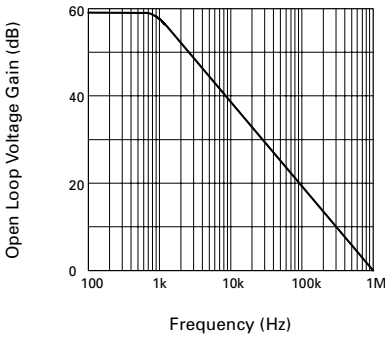


**V<sub>ref</sub> vs. Temperature**

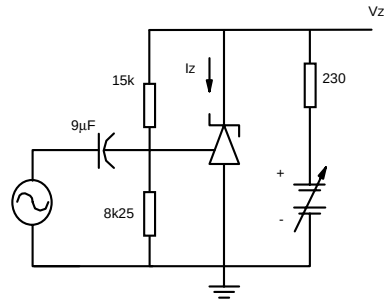


**Power Dissipation Derating**

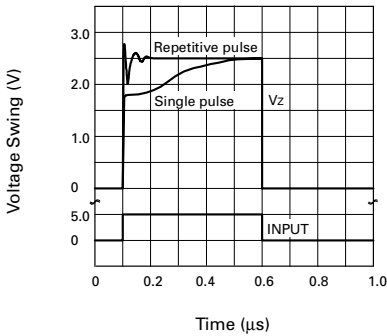
## TYPICAL CHARACTERISTICS



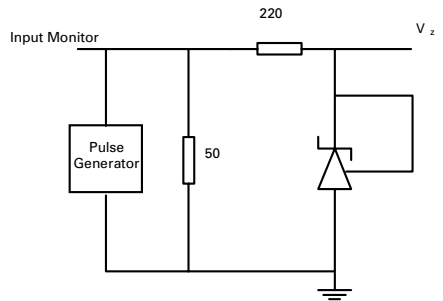
**Gain v Frequency**



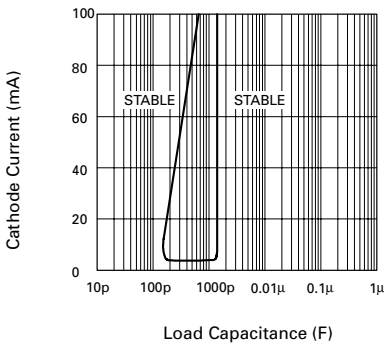
**Test Circuit for Open Loop Voltage Gain**



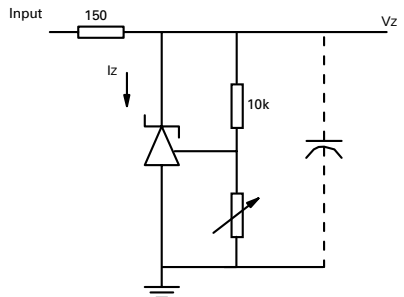
**Pulse Response**



**Test Circuit for Pulse Response**



**Stability Boundary Conditions**



**Test Circuit for Stability Boundary Conditions**

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## DC TEST CIRCUITS

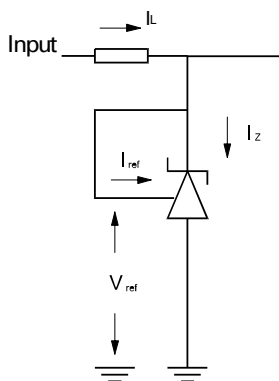


Fig 1 – Test Circuit for  $V_z = V_{ref}$

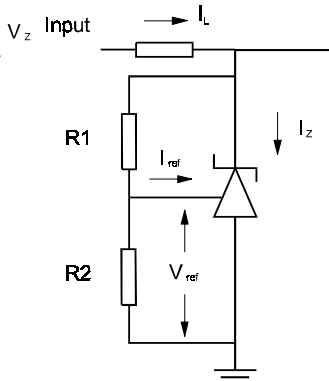


Fig 2 – Test Circuit for  $V_z > V_{ref}$

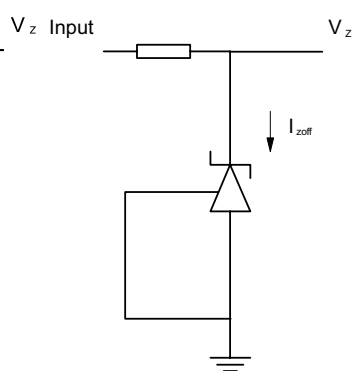
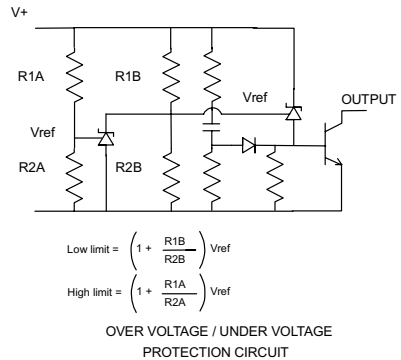
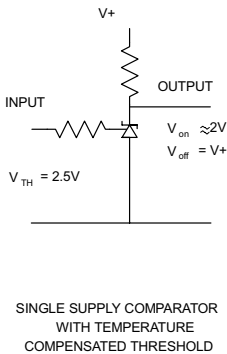
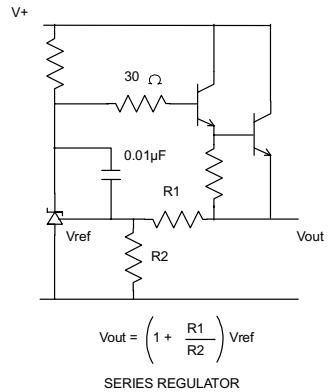
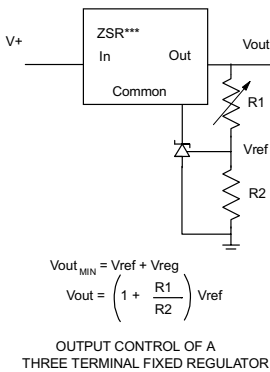
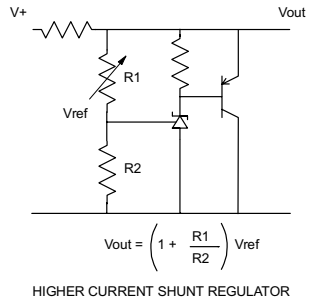
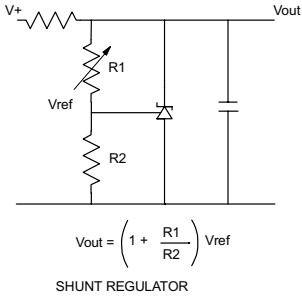


Fig 3 – Test Circuit for Off State current  $I_{zoff}$

### NOTE

† Since the "Off State" disables all internal circuitry including leakage control, operating in this mode at high temperature is not recommended.

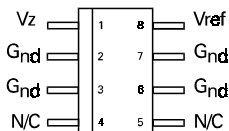
## APPLICATION CIRCUITS



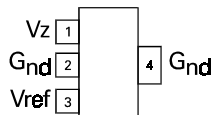
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## CONNECTION DIAGRAMS

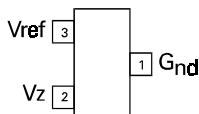
### SO8 Package Suffix – N8



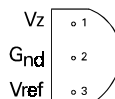
### SOT223 Package Suffix – G



### SOT23 Package Suffix – F



### TO92 Package Suffix – C



## ORDERING INFORMATION

| PART No    | TOL<br>% | PACKAGE | PARTMARK |
|------------|----------|---------|----------|
| ZHT431N802 | 2        | SO8     | ZHT43102 |
| ZHT431N801 | 1        | SO8     | ZHT43101 |
| ZHT431G02  | 2        | SOT223  | ZHT43102 |
| ZHT431G01  | 1        | SOT223  | ZHT43101 |
| ZHT431F02  | 2        | SOT23   | 43D      |
| ZHT431F01  | 1        | SOT23   | 43C      |
| ZHT431C02  | 2        | TO92    | ZHT43102 |
| ZHT431C01  | 1        | TO92    | ZHT43101 |
| ZHT431Z02  | 2        | SOT89   | 43F      |
| ZHT431Z01  | 1        | SOT89   | 43E      |

### SOT89 Package Suffix – Z

